

## D1199-G50C-9

## **High Power AO Modulator/Deflector**



0417

## **APPLICATIONS**

- Material Processing
- Via Hole Drilling
- Surface texturing

## **FEATURES**

- Low loss
  High Optical Down
- High Optical Power
- All Solid-State

The D1199-G50 series is an alternative to the AOM650 series. Both models are designed to minimize thermal lensing and reduce beam degradation at high powers pulsed systems. The D1199 differs in that the coolant is not in direct contact with the Germanium block and is ideally suited to pulsed laser / duty cycled systems. The D1199 can be used as a high power intensity modulator and/or medium resolution AO deflector.

SPECIFICATIONS (TYPICAL)		
Operating Wavelength: Interaction Material:	9 - 11µm (standard) Germanium	
Active Aperture: H=7 H=9	7mmH x 30mmW 9mmH x 30mmW	
Centre Frequency (fc): FM Bandwidth: Diffraction Efficiency: RF Power for Max. D/E Static Insertion Loss: Maximum Optical Power:	50MHz 20MHz > 85% at fc, 90% typical < 150 Watts total < 4% 600 Watts, 7mm dia. Gau	ussian beam
Bragg Angle: Separation Angle: Scan Angle (20MHz delta freq):	<u>9.4um</u> 42.7 mrad 85.5 mrad 34.2 mrad	<u>10.6um</u> 48.3 mrad 96.5 mrad 38.5 mrad
Laser Polarization: Water Cooling (Minimum):	Linear, Horizontal 2 Liter/Min. @ < 20⁰C	
<u>Modulator performance</u> : 7 mm beam diamet Diffraction Efficiency Optical Rise Time	ter >85% 0.83usec	
<u>Deflector Performance</u> : 7 x 30mm beam Diffraction Efficiency Access Time: Resolution:	> 80% across scan 5.5µsec 100	
<u>Drivers</u> Single spot Modulator: Dual spot modulator: Scan Line Deflector:	RFA250-2 (50MHz) RFA4060-2 iMS4-L, RFA200-2	
Options: -BR: Brass case parts * : other wavelengths in the 2.5μ	ιm - 11.2μm range.	
		Quality Assured

ALL SPECIFICATIONS SUBJECT TO CHANGE WITHOUT NOTICEISOMET CORP, 5263 Port Royal Rd, Springfield, VA 22151, USA.Tel: (703) 321 8301Fax: (703) 321 8546E-mail: ISOMET@ ISOMET.COMWeb Page: WWW.ISOMET.COM

Quality Assured. In-house: Crystal Growth, Optical Polishing, A/R coating, Vacuum Bonding

